NSN 5962-01-088-1631

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View Online at https://aerobasegroup.com/nsn/5962-01-088-1631

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 ir	iches and 0.310 inches
Body Height:	
Between 0.140 ir	iches and 0.185 inches
Maximum Powe	r Dissipation Rating:
715.0 milliwatts	
Operating Temp	urature Range:
-55.0/+125.0 deg	rees celsius
Storage Tempur	ature Range:
-65.0/+150.0 deg	rees celsius
End Application	:
Radar set, type a	n/fps-115
Features Provid	ed:
Hermetically seal	ed and monolithic and positive outputs and w/storage and programmable and programmed and schottky and w/enable
Inclosure Mater	al:
Ceramic and glas	SS
Inclosure Config	guration:
Dual-in-line	
Output Logic Fo	orm:
Transistor-transis	stor logic
Input Circuit Pat	itern:
10 input	
Case Outline Sc	urce And Designator:
D-2 mil-m-38510	
Terminal Surfac	e Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
5.5 volts powers	source
Time Rating Per	Chacteristic:
40.00 nanosecor	ds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Туре:
Rom	
Memory Capaci	ty:
Unknown	
Test Data Docu	nent:
49956-952369 dr	awing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any spe	cification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type A	nd Quantity:

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

